

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: :
Euijoon Yoon ea al. : Examiner: MALDONADO, JULIO J
Serial No.: 10/563,854 : Group Art Unit: 2823
Filed: June 9, 2006 : Attorney Docket No.: 504478.24
For: GROWTH METHOD FOR NITRIDE :
SEMICONDUCTOR EPITAXIAL LAYERS: Customer No.: 27128
: Confirmation No.: 3828
Last Office Action: June 9, 2010 :

AMENDMENT AFTER RCE

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In response to the Office Action mailed June 9, 2010, please amend the above-identified application in accordance with the amendments and remarks as set forth herein.

Amendments to the Claims are reflected in the listing of claims which begin on page 2 of this document.

Remarks/Arguments begin on page 6 of this document.